

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

Features.

- *Low Forward Voltage.
- *Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- $\ast\, {\rm Low} \ {\rm Power} \ {\rm Loss} \ \& \ {\rm High} \ {\rm efficiency}.$
- *175℃ Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

* In compliance with EU RoHs 2002/95/EC directives

Flammability Classification 94V-O

P

3.4

R_{θjc}

°C/w

MAXIMUM RATINGS

Characteristic	Symbol	MBR20100CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	v
RMS Reverse Voltage	V _{R(RMS)}	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C =125 $^\circ$ C	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	150	А
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175	°C
THERMAL RESISTANCES			

ELECTRIAL CHARACTERISTICS

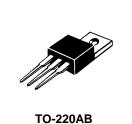
Typical Thermal Resistance junction to case

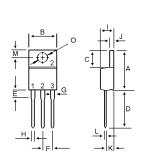
Characteristic	Symbol	MBR20100CT	Unit
$ \begin{array}{l} \mbox{Maximum Instantaneous Forward Voltage} & (\mbox{ per diode}) \\ (I_F = 10 \mbox{ Amp } T_C = 25^\circ \mbox{C}) \\ (I_F = 10 \mbox{ Amp } T_C = 125^\circ \mbox{C}) \end{array} $	V _F	0.85 0.76	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R	0.01 10	mA

MBR20100CT

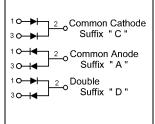
SCHOTTKY BARRIER RECTIFIERS

> 20 AMPERES 100 VOLTS





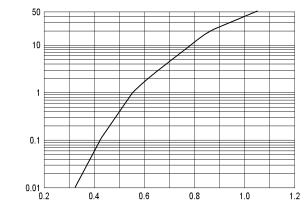
DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	14.68	15.32		
В	9.78	10.42		
С	5.02	6.52		
D	13.06	14.62		
E	3.57	4.07		
F	2.42	2.66		
G	1.12	1.36		
н	0.72	0.96		
1	4.22	4.98		
J	1.14	1.38		
К	2.20	2.98		
L	0.33	0.55		
Μ	2.48	2.98		
0	3.70	3.90		



MBR20100CT

FIG-1 FORWARD CURRENT DERATING CURVE

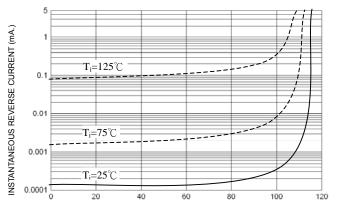
FIG-2 TYPICAL FORWARD CHARACTERISITICS



NSTANTANEOUS FORWARD CURRENT (Amp.)

FORWARD VOLTAGE (Volts)

FIG-3 TYPICAL REVERSE CHARACTERISTICS

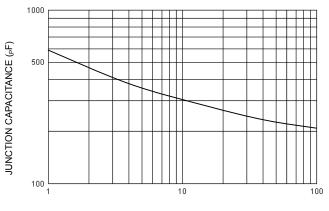


REVERSE VOLTAGE (Volts)

FIG-5 PEAK FORWARD SURGE CURRENT

NUMBER OF CYCLES AT 60 Hz

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)